

Dual 50MHz, Low Noise, Rail-to-Rail, CMOS Op Amp

FEATURES

- **Input Bias Current:** 1pA (Typ at 25°C)
- **Low Offset Voltage:** 100μV Max
- **Low Offset Drift:** 2.5μV/°C Max
- 0.1Hz to 10Hz Noise: 1.5μV_{P-P}
- Slew Rate: 40V/μs
- Gain Bandwidth Product: 50MHz
- Output Swings Rail-to-Rail
- Supply Operation:
2.8V to 6V LTC6244
2.8V to ±5.25V LTC6244HV
- Low Input Capacitance: 2.1pF
- Available in 8-Pin MSOP and Tiny DFN Packages

APPLICATIONS

- Photodiode Amplifiers
- Charge Coupled Amplifiers
- Low Noise Signal Processing
- Active Filters
- Medical Instrumentation
- High Impedance Transducer Amplifier

DESCRIPTION

The LTC®6244 is a dual high speed, unity-gain stable CMOS op amp that features a 50MHz gain bandwidth, 40V/μs slew rate, 1pA of input bias current, low input capacitance and rail-to-rail output swing. The 0.1Hz to 10Hz noise is just 1.5μV_{P-P} and 1kHz noise is guaranteed to be less than 12nV/√Hz. This excellent AC and noise performance is combined with wide supply range operation, a maximum offset voltage of just 100μV and drift of only 2.5μV/°C, making it suitable for use in many fast signal processing applications, such as photodiode amplifiers.

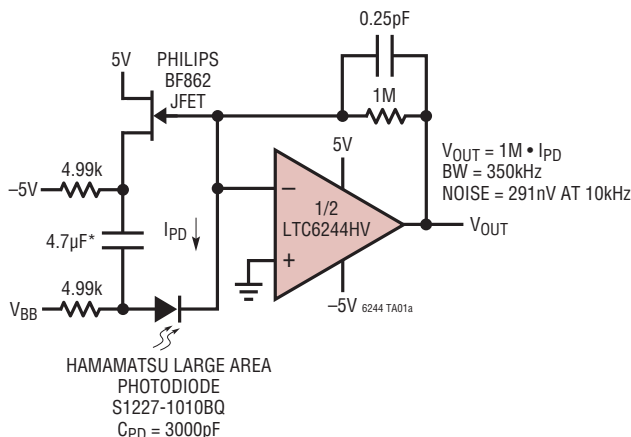
This op amp has an output stage that swings within 35mV of either supply rail to maximize the signal dynamic range in low supply applications. The input common mode range extends to the negative supply. It is fully specified on 3V and 5V, and an HV version guarantees operation on supplies of ±5V.

The LTC6244 is available in the 8-pin MSOP, and for compact designs, it is packaged in the tiny dual fine pitch lead free (DFN) package.

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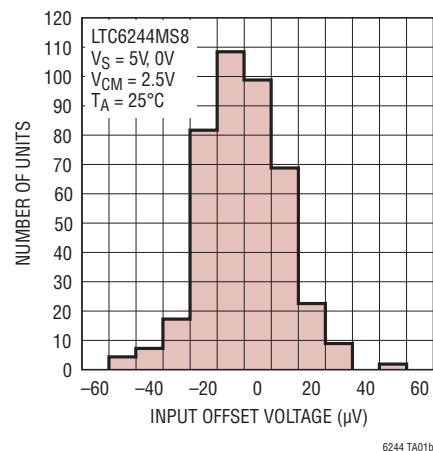
TYPICAL APPLICATION

Very Low Noise Large Area Photodiode



* CAN BE MICROPHONIC, FILM, X7R, IF NEEDED.

V_{OS} Distribution



LTC6244

ABSOLUTE MAXIMUM RATINGS (Note 1)

Total Supply Voltage (V^+ to V^-)

LTC6244 7V

LTC6244HV 12V

Input Voltage ($V^+ + 0.3V$) to ($V^- - 0.3V$)

Input Current $\pm 10mA$

Output Short Circuit Duration (Note 2) Indefinite

Operating Temperature Range

LTC6244C $-40^{\circ}C$ to $85^{\circ}C$

LTC6244I $-40^{\circ}C$ to $85^{\circ}C$

LTC6244H $-40^{\circ}C$ to $125^{\circ}C$

Specified Temperature Range (Note 3)

LTC6244C $0^{\circ}C$ to $70^{\circ}C$

LTC6244I $-40^{\circ}C$ to $85^{\circ}C$

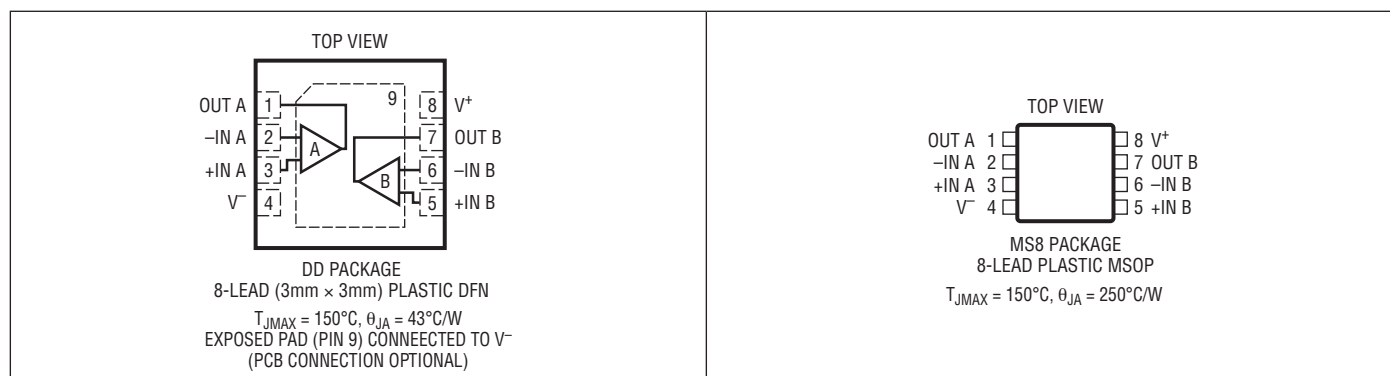
LTC6244H $-40^{\circ}C$ to $125^{\circ}C$

Junction Temperature $150^{\circ}C$

Storage Temperature Range $-65^{\circ}C$ to $150^{\circ}C$

Lead Temperature (Soldering, 10 sec) $300^{\circ}C$

PIN CONFIGURATION



ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE
LTC6244CDD#PBF	LTC6244CDD#TRPBF	LCCF	8-Lead (3mm \times 3mm) Plastic DFN	$0^{\circ}C$ to $70^{\circ}C$
LTC6244HVCDD#PBF	LTC6244HVCDD#TRPBF	LCGD	8-Lead (3mm \times 3mm) Plastic DFN	$0^{\circ}C$ to $70^{\circ}C$
LTC6244IDD#PBF	LTC6244IDD#TRPBF	LCCF	8-Lead (3mm \times 3mm) Plastic DFN	$-40^{\circ}C$ to $85^{\circ}C$
LTC6244HVIDD#PBF	LTC6244HVIDD#TRPBF	LCGD	8-Lead (3mm \times 3mm) Plastic DFN	$-40^{\circ}C$ to $85^{\circ}C$
LTC6244HDD#PBF	LTC6244HDD#TRPBF	LCCF	8-Lead (3mm \times 3mm) Plastic DFN	$-40^{\circ}C$ to $125^{\circ}C$
LTC6244HVHDD#PBF	LTC6244HVHDD#TRPBF	LCGD	8-Lead (3mm \times 3mm) Plastic DFN	$-40^{\circ}C$ to $125^{\circ}C$
LTC6244CMS8#PBF	LTC6244CMS8#TRPBF	LTCCM	8-Lead Plastic MSOP	$0^{\circ}C$ to $70^{\circ}C$
LTC6244HVCMS8#PBF	LTC6244HVCMS8#TRPBF	LTCCF	8-Lead Plastic MSOP	$0^{\circ}C$ to $70^{\circ}C$
LTC6244IMS8#PBF	LTC6244IMS8#TRPBF	LTCCM	8-Lead Plastic MSOP	$-40^{\circ}C$ to $85^{\circ}C$
LTC6244HVIMS8#PBF	LTC6244HVIMS8#TRPBF	LTCCF	8-Lead Plastic MSOP	$-40^{\circ}C$ to $85^{\circ}C$
LTC6244HMS8#PBF	LTC6244HMS8#TRPBF	LTCCM	8-Lead Plastic MSOP	$-40^{\circ}C$ to $125^{\circ}C$

Consult LTC Marketing for parts specified with wider operating temperature ranges.

Consult LTC Marketing for information on non-standard lead based finish parts.

For more information on lead free part marking, go to: <http://www.linear.com/leadfree/>

For more information on tape and reel specifications, go to: <http://www.linear.com/tapeandreel/>

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ELECTRICAL CHARACTERISTICS

(LTC6244C/I, LTC6244HVC/I) The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = 5\text{V}$, 0V , $V_{CM} = 2.5\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage (Note 4)	MS8 Package 0°C to 70°C -40°C to 85°C	●	40	100 225 300	μV μV μV
		DD Package 0°C to 70°C -40°C to 85°C	● ●	100	650 800 950	μV μV μV
	V_{OS} Match Channel-to-Channel (Note 5)	MS8 Package 0°C to 70°C -40°C to 85°C	● ●	40	160 275 325	μV μV μV
		DD Package 0°C to 70°C -40°C to 85°C	● ●	150	800 900 1.1	μV μV mV
	TC V_{OS}	Input Offset Voltage Drift, MS8 (Note 6)	●	0.7	2.5	$\mu\text{V}/^\circ\text{C}$
	I_B	Input Bias Current (Notes 4, 7)	●	1	75	pA pA
I_{OS}	Input Offset Current (Notes 4, 7)		●	0.5	75	pA pA
	Input Noise Voltage	0.1Hz to 10Hz		1.5		μV_{P-P}
e_n	Input Noise Voltage Density	$f = 1\text{kHz}$		8	12	$\text{nV}/\sqrt{\text{Hz}}$
i_n	Input Noise Current Density (Note 8)			0.56		$\text{fA}/\sqrt{\text{Hz}}$
R_{IN}	Input Resistance	Common Mode		10^{12}		Ω
C_{IN}	Input Capacitance Differential Mode Common Mode	$f = 100\text{kHz}$		3.5		pF
				2.1		pF
V_{CM}	Input Voltage Range	Guaranteed by CMRR	●	0	3.5	V
CMRR	Common Mode Rejection	$0\text{V} \leq V_{CM} \leq 3.5\text{V}$	●	74	105	dB
	CMRR Match Channel-to-Channel (Note 5)		●	72	100	dB
A_{VOL}	Large Signal Voltage Gain	$V_0 = 1\text{V}$ to 4V $R_L = 10\text{k}$ to $V_S/2$ 0°C to 70°C -40°C to 85°C	● ●	1000 600 450	2500	V/mV V/mV V/mV
		$V_0 = 1.5\text{V}$ to 3.5V $R_L = 1\text{k}$ to $V_S/2$ 0°C to 70°C -40°C to 85°C	● ●	300 200 150	1000	V/mV V/mV V/mV
	V_{OL}	Output Voltage Swing Low (Note 9) No Load $I_{SINK} = 1\text{mA}$ $I_{SINK} = 5\text{mA}$	● ● ●	15 40 150	35 75 300	mV mV mV
			● ● ●	15 45 175	35 75 325	mV mV mV
PSRR	Power Supply Rejection	$V_S = 2.8\text{V}$ to 6V , $V_{CM} = 0.2\text{V}$	●	75	105	dB
	PSRR Match Channel-to-Channel (Note 5)		●	73	100	dB
	Minimum Supply Voltage (Note 10)		●	2.8		V
I_{SC}	Short-Circuit Current		●	25	35	mA
I_S	Supply Current per Amplifier		●	6.25	7.4	mA

ELECTRICAL CHARACTERISTICS

(LTC6244C/I, LTC6244HVC/I) The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = 5\text{V}$, 0V , $V_{CM} = 2.5\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
GBW	Gain Bandwidth Product	Frequency = 100kHz, $R_L = 1\text{k}\Omega$	● 35	50		MHz
SR	Slew Rate (Note 11)	$A_V = -2$, $R_L = 1\text{k}\Omega$	● 18	35		V/ μs
FPBW	Full Power Bandwidth (Note 12)	$V_{OUT} = 3V_{P-P}$, $R_L = 1\text{k}\Omega$	● 1.9	3.7		MHz
t_s	Settling Time	$V_{STEP} = 2\text{V}$, $A_V = -1$, $R_L = 1\text{k}\Omega$, 0.1%		535		ns

(LTC6244C/I, LTC6244HVC/I) The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = 3\text{V}$, 0V , $V_{CM} = 1.5\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage (Note 4)	MS8 Package 0°C to 70°C	●	40	175	μV
		-40°C to 85°C	●		250	μV
		DD Package 0°C to 70°C	●	100	650	μV
		-40°C to 85°C	●		800	μV
	V_{OS} Match Channel-to-Channel (Note 5)	MS8 Package 0°C to 70°C	●	40	200	μV
		-40°C to 85°C	●		300	μV
I_B	Input Bias Current (Notes 4, 7)	DD Package 0°C to 70°C	●	150	800	μV
		-40°C to 85°C	●		900	μV
I_{OS}	Input Offset Current (Notes 4, 7)		●		1.1	mV
I_B	Input Bias Current (Notes 4, 7)		●	1	75	pA
I_{OS}	Input Offset Current (Notes 4, 7)		●	0.5	75	pA
	Input Noise Voltage	0.1Hz to 10Hz		1.5		μV_{P-P}
e_n	Input Noise Voltage Density	$f = 1\text{kHz}$		8	12	nV/ $\sqrt{\text{Hz}}$
i_n	Input Noise Current Density (Note 8)			0.56		fA/ $\sqrt{\text{Hz}}$
V_{CM}	Input Voltage Range	Guaranteed by CMRR	● 0		1.5	V
CMRR	Common Mode Rejection	$0\text{V} \leq V_{CM} \leq 1.5\text{V}$	● 70	105		dB
	CMRR Match Channel-to-Channel (Note 5)		● 68	100		dB
A_{VOL}	Large Signal Voltage Gain	$V_O = 1\text{V}$ to 2V $R_L = 10\text{k}\Omega$ to $V_S/2$ 0°C to 70°C -40°C to 85°C	● 200 ● 100 ● 85	800		V/mV V/mV V/mV
V_{OL}	Output Voltage Swing Low (Note 9)	No Load $I_{SINK} = 1\text{mA}$	● 12 ● 45	30 110		mV mV
V_{OH}	Output Voltage Swing High (Note 9)	No Load $I_{SOURCE} = 1\text{mA}$	● 12 ● 50	30 110		mV mV
PSRR	Power Supply Rejection	$V_S = 2.8\text{V}$ to 6V , $V_{CM} = 0.2\text{V}$	● 75	105		dB
	PSRR Match Channel-to-Channel (Note 5)		● 73	100		dB
	Minimum Supply Voltage (Note 10)		● 2.8			V
I_{SC}	Short-Circuit Current		● 8	15		mA

ELECTRICAL CHARACTERISTICS

(LTC6244C/I, LTC6244HVC/I) The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = 3\text{V}$, 0V , $V_{CM} = 1.5\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
I_S	Supply Current per Amplifier	●		4.8	5.8	mA
GBW	Gain Bandwidth Product	Frequency = 100kHz, $R_L = 1\text{k}\Omega$ ●	35	50		MHz

(LTC6244HVC/I) The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = \pm 5\text{V}$, 0V , $V_{CM} = 0\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage (Note 4)	MS8 Package 0°C to 70°C -40°C to 85°C ●		50	220	μV
		●			275	μV
	DD Package 0°C to 70°C -40°C to 85°C ●	●		100	700	μV
		●			800	μV
V_{OS} Match Channel-to-Channel (Note 5)	MS8 Package 0°C to 70°C -40°C to 85°C ●	●		50	250	μV
		●			325	μV
	DD Package 0°C to 70°C -40°C to 85°C ●	●		150	900	μV
		●			1000	μV
TC V_{OS}	Input Offset Voltage Drift, MS8 (Note 6)	●		0.7	2.5	$\mu\text{V}/^\circ\text{C}$
I_B	Input Bias Current (Notes 4, 7)	●		1	75	pA
I_{OS}	Input Offset Current (Notes 4, 7)	●		0.5	75	pA
	Input Noise Voltage	0.1Hz to 10Hz		1.5		μV_{P-P}
e_n	Input Noise Voltage Density	$f = 1\text{kHz}$		8	12	$\text{nV}/\sqrt{\text{Hz}}$
i_n	Input Noise Current Density (Note 8)			0.56		$\text{fA}/\sqrt{\text{Hz}}$
R_{IN}	Input Resistance	Common Mode		10^{12}		Ω
C_{IN}	Input Capacitance Differential Mode Common Mode	$f = 100\text{kHz}$		3.5		pF
				2.1		pF
V_{CM}	Input Voltage Range	Guaranteed by CMRR ●	-5		3.5	V
CMRR	Common Mode Rejection	$-5\text{V} \leq V_{CM} \leq 3.5\text{V}$ ●	80	105		dB
	CMRR Match Channel-to-Channel (Note 5)	●	78	95		dB
A_{VOL}	Large Signal Voltage Gain	$V_O = -3.5\text{V}$ to 3.5V $R_L = 10\text{k}$ 0°C to 70°C -40°C to 85°C ●	2500	6000		V/mV
		●	1500			V/mV
	$R_L = 1\text{k}$ 0°C to 70°C -40°C to 85°C ●	●	700	3500		V/mV
		●	400			V/mV
V_{OL}	Output Voltage Swing Low (Note 9)	No Load ●		15	40	mV
		$I_{SINK} = 1\text{mA}$ ●		45	75	mV
		$I_{SINK} = 10\text{mA}$ ●		360	550	mV
V_{OH}	Output Voltage Swing High (Note 9)	No Load ●		15	40	mV
		$I_{SOURCE} = 1\text{mA}$ ●		45	75	mV
		$I_{SOURCE} = 10\text{mA}$ ●		360	550	mV

ELECTRICAL CHARACTERISTICS (LTC6244HVC/I) The ● denotes the specifications which apply over the specified temperature range, otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = \pm 5\text{V}$, 0V , $V_{CM} = 0\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
PSRR	Power Supply Rejection	$V_S = 2.8\text{V}$ to 10.5V , $V_{CM} = 0.2\text{V}$	●	75	110		dB
	PSRR Match Channel-to-Channel (Note 5)		●	73	106		dB
	Minimum Supply Voltage (Note 10)		●	2.8			V
I_{SC}	Short-Circuit Current		●	40	55		mA
I_S	Supply Current per Amplifier		●		7	8.8	mA
GBW	Gain Bandwidth Product	Frequency = 100kHz , $R_L = 1\text{k}\Omega$	●	35	50		MHz
SR	Slew Rate (Note 11)	$A_V = -2$, $R_L = 1\text{k}\Omega$	●	18	40		V/ μs
FPBW	Full Power Bandwidth (Note 12)	$V_{OUT} = 3V_{P-P}$, $R_L = 1\text{k}\Omega$	●	1.9	4.25		MHz
t_s	Settling Time	$V_{STEP} = 2\text{V}$, $A_V = -1$, $R_L = 1\text{k}\Omega$, 0.1%			330		ns

(LTC6244H) The ● denotes the specifications which apply from -40°C to 125°C , otherwise specifications are at $T_A = 25^\circ\text{C}$. $V_S = 5\text{V}$, 0V , $V_{CM} = 2.5\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage (Note 4)	MS8 Package	●		40	125 400	μV μV
		DD8 Package	●		100	650 950	μV μV
	V_{OS} Match Channel-to-Channel (Note 5)	MS8 Package	●		40	160 400	μV μV
		DD8 Package -40°C to 125°C	●		150	800 1160	μV μV
TC V_{OS}	Input Offset Voltage Drift, MS8 (Note 6)		●		0.7	2.5	$\mu\text{V}/^\circ\text{C}$
I_B	Input Bias Current (Notes 4, 7)		●		1	2	pA nA
I_{OS}	Input Offset Current (Notes 4, 7)		●		0.5	250	pA pA
V_{CM}	Input Voltage Range	Guaranteed by CMRR	●	0		3.5	V
CMRR	Common Mode Rejection	$0\text{V} \leq V_{CM} \leq 3.5\text{V}$	●	74			dB
	CMRR Match Channel-to-Channel (Note 5)		●	72			dB
A_{VOL}	Large Signal Voltage Gain	$V_O = 1\text{V}$ to 4V $R_L = 10\text{k}$ to $V_S/2$	●	350			V/mV
		$V_O = 1.5\text{V}$ to 3.5V $R_L = 1\text{k}$ to $V_S/2$	●	125			V/mV
V_{OL}	Output Voltage Swing Low (Note 9)	No Load	●			40	mV
		$I_{SINK} = 1\text{mA}$	●			85	mV
		$I_{SINK} = 5\text{mA}$	●			325	mV
V_{OH}	Output Voltage Swing High (Note 9)	No Load	●			40	mV
		$I_{SOURCE} = 1\text{mA}$	●			85	mV
		$I_{SOURCE} = 5\text{mA}$	●			325	mV

ELECTRICAL CHARACTERISTICS

(LTC6244H) The ● denotes the specifications which apply from -40°C to 125°C , otherwise specifications are at $T_A = 25^{\circ}\text{C}$. $V_S = 5\text{V}$, 0V , $V_{CM} = 2.5\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
PSRR	Power Supply Rejection	$V_S = 2.8\text{V}$ to 6V , $V_{CM} = 0.2\text{V}$	●	75		dB
	PSRR Match Channel-to-Channel (Note 5)		●	73		dB
	Minimum Supply Voltage (Note 10)		●	2.8		V
I_{SC}	Short-Circuit Current		●	20		mA
I_S	Supply Current per Amplifier		●	6.25	7.4	mA
GBW	Gain Bandwidth Product	Frequency = 100kHz , $R_L = 1\text{k}\Omega$	●	30		MHz
SR	Slew Rate (Note 11)	$A_V = -2$, $R_L = 1\text{k}\Omega$	●	17		V/ μs
FPBW	Full Power Bandwidth (Note 12)	$V_{OUT} = 3V_{P-P}$, $R_L = 1\text{k}\Omega$	●	1.8		MHz

(LTC6244H) The ● denotes the specifications which apply from -40°C to 125°C , otherwise specifications are at $T_A = 25^{\circ}\text{C}$. $V_S = 3\text{V}$, 0V , $V_{CM} = 1.5\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage (Note 4)	MS8 Package	●	40	175 400	μV μV
		DD8 Package	●	100	650 950	μV μV
	V_{OS} Match Channel-to-Channel (Note 5)	MS8 Package	●	40	160 400	μV μV
		DD8 Package	●	150	800 1200	μV μV
I_B	Input Bias Current (Notes 4, 7)		●	1	2	pA nA
I_{OS}	Input Offset Current (Notes 4, 7)		●	0.5	250	pA pA
V_{CM}	Input Voltage Range	Guaranteed by CMRR	●	0	1.5	V
CMRR	Common Mode Rejection	$0\text{V} \leq V_{CM} \leq 1.5\text{V}$	●	70		dB
	CMRR Match Channel-to-Channel (Note 5)		●	68		dB
A_{VOL}	Large Signal Voltage Gain	$V_O = 1\text{V}$ to 2V $R_L = 10\text{k}$ to $V_S/2$	●	75		V/mV
V_{OL}	Output Voltage Swing Low (Note 9)	No Load $I_{SINK} = 1\text{mA}$	● ●		30 110	mV mV
V_{OH}	Output Voltage Swing High (Note 9)	No Load $I_{SOURCE} = 1\text{mA}$	● ●		30 110	mV mV
PSRR	Power Supply Rejection	$V_S = 2.8\text{V}$ to 6V , $V_{CM} = 0.2\text{V}$	●	75		dB
	PSRR Match Channel-to-Channel (Note 5)		●	73		dB
	Minimum Supply Voltage (Note 10)		●	2.8		V
I_{SC}	Short-Circuit Current		●	5		mA
I_S	Supply Current per Amplifier		●	4.8	5.8	mA
GBW	Gain Bandwidth Product	Frequency = 100kHz , $R_L = 1\text{k}\Omega$	●	28		MHz

ELECTRICAL CHARACTERISTICS (LTC6244HVH) The ● denotes the specifications which apply from -40°C to 125°C , otherwise specifications are at $T_A = 25^{\circ}\text{C}$. $V_S = \pm 5\text{V}$, $V_{CM} = 0\text{V}$ unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage (Note 4)	DD8 Package	●	100	700 1050	μV μV
	V_{OS} Match Channel-to-Channel (Note 5)	DD8 Package	●	150	900 1165	μV μV
$TC\ V_{OS}$	Input Offset Voltage Drift, MS8 (Note 6)		●	0.7	2.5	$\mu\text{V}/^{\circ}\text{C}$
I_B	Input Bias Current (Notes 4, 7)		●	1	2	pA nA
I_{OS}	Input Offset Current (Notes 4, 7)		●	0.5	250	pA nA
	Input Noise Voltage	0.1Hz to 10Hz		1.5		μV_{P-P}
e_n	Input Noise Voltage Density	$f = 1\text{kHz}$		8	12	$\text{nV}/\sqrt{\text{Hz}}$
i_n	Input Noise Current Density (Note 8)			0.56		$\text{fA}/\sqrt{\text{Hz}}$
R_{IN}	Input Resistance	Common Mode		10^{12}		Ω
C_{IN}	Input Capacitance Differential Mode Common Mode	$f = 100\text{kHz}$		3.5 2.1		pF pF
V_{CM}	Input Voltage Range	Guaranteed by CMRR	●	-5	3.5	V
CMRR	Common Mode Rejection	$-5\text{V} \leq V_{CM} \leq 3.5\text{V}$	●	80	105	dB
	CMRR Match Channel-to-Channel (Note 5)		●	78	95	dB
A_{VOL}	Large Signal Voltage Gain	$V_O = -3.5\text{V}$ to 3.5V $R_L = 10\text{k}$	●	2500 1000	6000	V/mV V/mV
		$R_L = 1\text{k}$	●	700 170	3500	V/mV V/mV
V_{OL}	Output Voltage Swing Low (Note 9)	No Load $I_{SINK} = 1\text{mA}$ $I_{SINK} = 10\text{mA}$	● ● ●	15 45 360	40 75 550	mV mV mV
V_{OH}	Output Voltage Swing High (Note 9)	No Load $I_{SOURCE} = 1\text{mA}$ $I_{SINK} = 10\text{mA}$	● ● ●	15 45 360	40 75 550	mV mV mV
PSRR	Power Supply Rejection	$V_S = 2.8\text{V}$ to 10.5V , $V_{CM} = 0.2\text{V}$	●	75	110	dB
	PSRR Match Channel-to-Channel (Note 5)		●	73	106	dB
	Minimum Supply Voltage (Note 10)		●	2.8		V
I_{SC}	Short-Circuit Current		●	40	55	mA
I_S	Supply Current per Amplifier		●		9.3	mA
GBW	Gain Bandwidth Product	Frequency = 100kHz , $R_L = 1\text{k}\Omega$	●	35	50	MHz
SR	Slew Rate (Note 11)	$A_V = -2$, $R_L = 1\text{k}\Omega$	●	18	40	$\text{V}/\mu\text{s}$
FPBW	Full Power Bandwidth (Note 12)	$V_{OUT} = 3V_{P-P}$, $R_L = 1\text{k}\Omega$	●	1.9	4.3	MHz
t_s	Settling Time	$V_{OUT} = 2\text{V}$, $A_V = -1$, $R_L = 1\text{k}\Omega$	●		330	ns

ELECTRICAL CHARACTERISTICS

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 2: A heat sink may be required to keep the junction temperature below the absolute maximum rating when the output is shorted indefinitely.

Note 3: The LTC6244C/LTC6244HVC are guaranteed to meet specified performance from 0°C to 70°C. They are designed, characterized and expected to meet specified performance from –40°C to 85°C, but are not tested or QA sampled at these temperatures. The LTC6244I/LTC6244HVI, are guaranteed to meet specified performance from –40°C to 85°C. The LTC6244H is guaranteed to meet specified performance from –40°C to 125°C.

Note 4: ESD (Electrostatic Discharge) sensitive device. ESD protection devices are used extensively internal to the LTC6244; however, high electrostatic discharge can damage or degrade the device. Use proper ESD handling precautions.

Note 5: Matching parameters are the difference between the two amplifiers of the LTC6244. CMRR and PSRR match are defined as follows: CMRR and PSRR are measured in $\mu\text{V/V}$ on the amplifiers. The difference is calculated between the sides in $\mu\text{V/V}$. The result is converted to dB.

Note 6: This parameter is not 100% tested.

Note 7: This specification is limited by high speed automated test capability. See Typical Characteristics curves for actual typical performance.

Note 8: Current noise is calculated from the formula: $i_n = (2qI_B)^{1/2}$ where $q = 1.6 \times 10^{-19}$ coulomb. The noise of source resistors up to 50G Ω dominates the contribution of current noise. See also Typical Characteristics curve Noise Current vs Frequency.

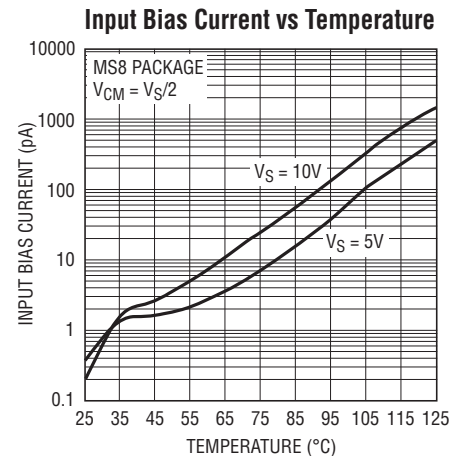
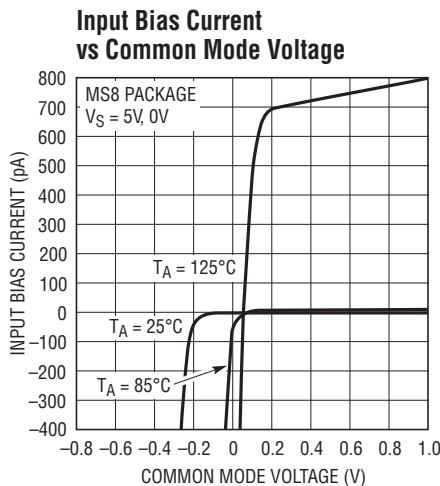
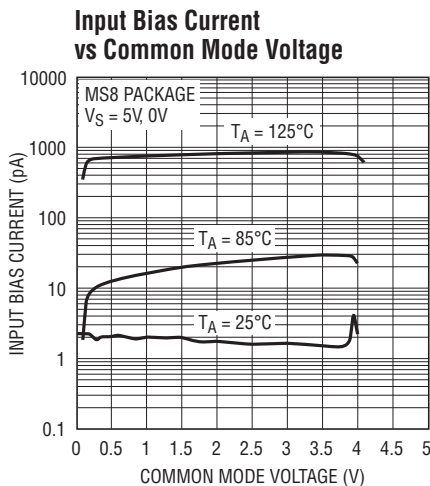
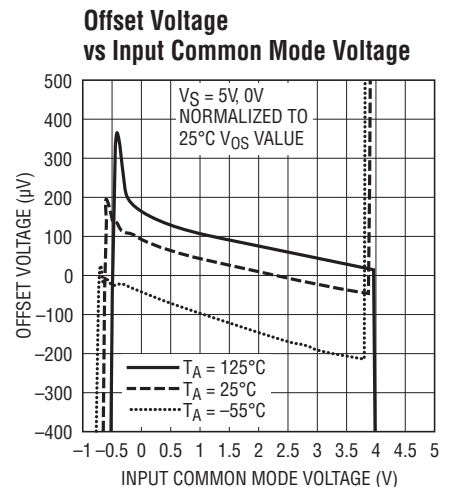
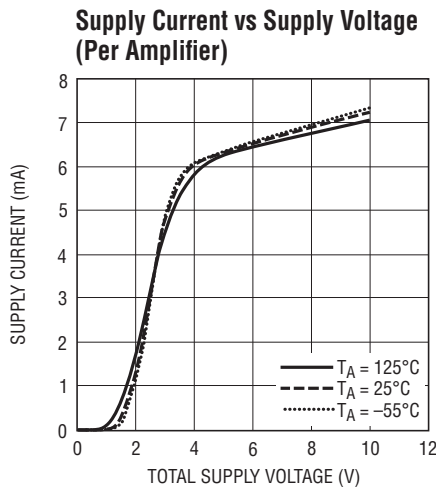
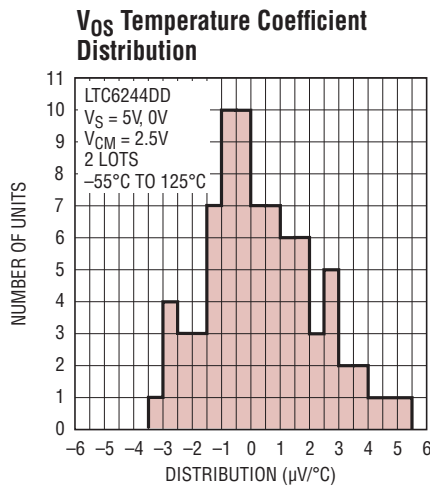
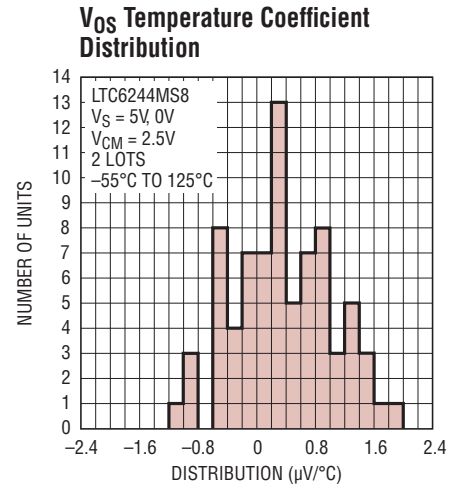
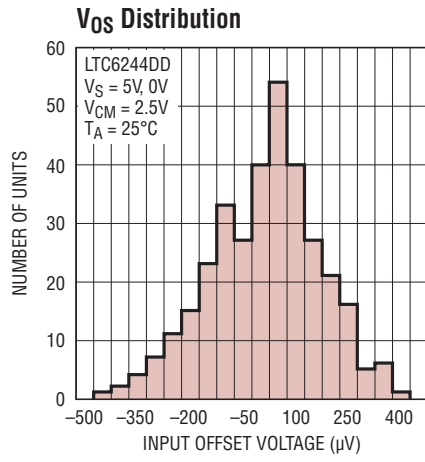
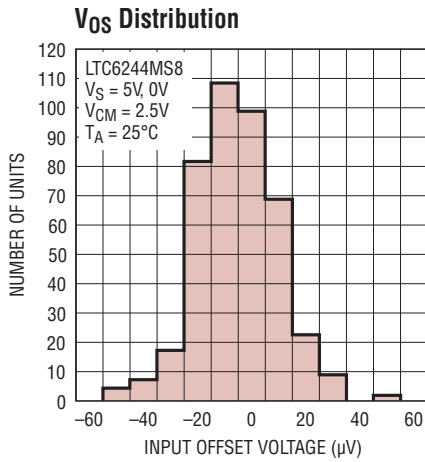
Note 9: Output voltage swings are measured between the output and power supply rails.

Note 10: Minimum supply voltage is guaranteed by the power supply rejection ratio test.

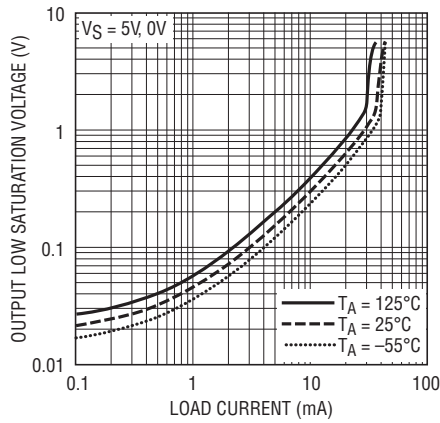
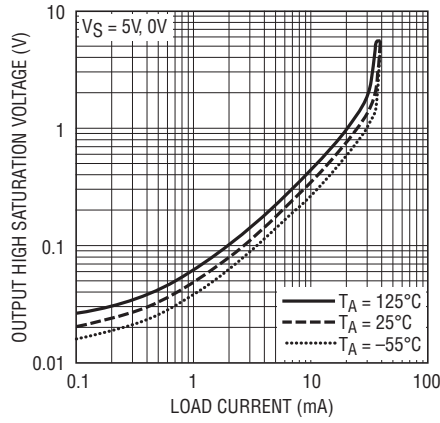
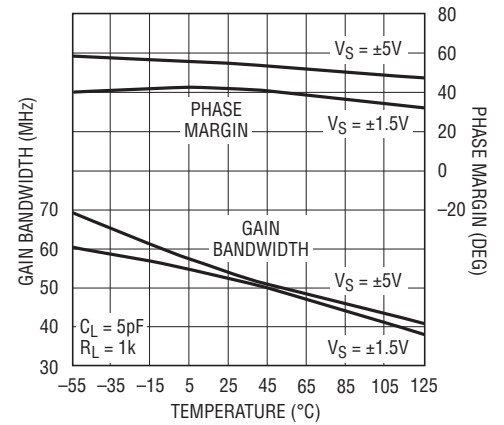
Note 11: Slew rate is measured in a gain of –2 with $R_F = 1\text{k}$ and $R_G = 500\Omega$. V_{IN} is $\pm 1\text{V}$ and V_{OUT} slew rate is measured between –1V and +1V. On the LTC6244HV/LTC6245HV, V_{IN} is $\pm 2\text{V}$ and V_{OUT} slew rate is measured between –2V and +2V.

Note 12: Full-power bandwidth is calculated from the slew rate: $\text{FPBW} = \text{SR}/2\pi V_P$.

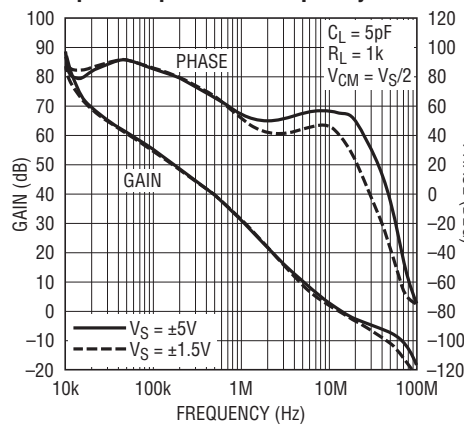
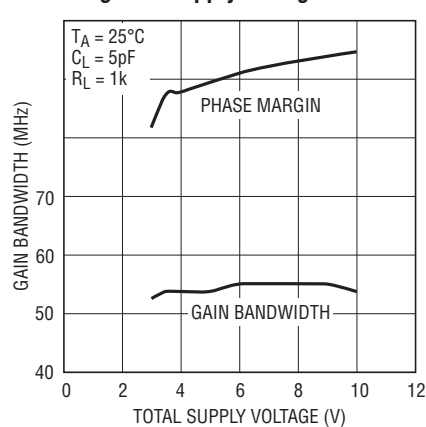
TYPICAL PERFORMANCE CHARACTERISTICS



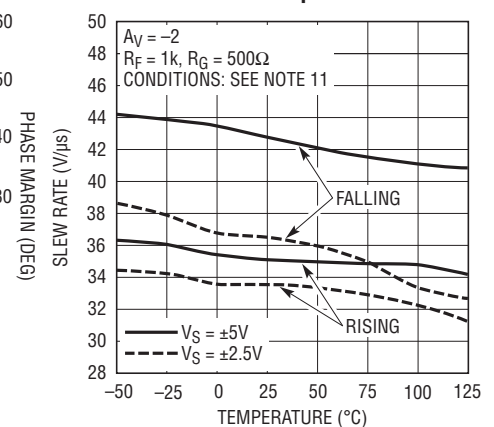
TYPICAL PERFORMANCE CHARACTERISTICS

Output Saturation Voltage
vs Load Current (Output Low)Output Saturation Voltage
vs Load Current (Output High)Gain Bandwidth and Phase
Margin vs Temperature

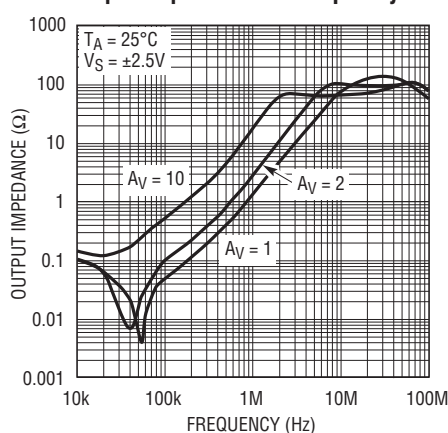
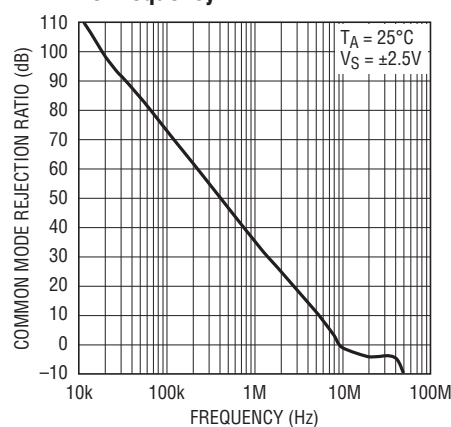
Open Loop Gain vs Frequency

Gain Bandwidth and Phase
Margin vs Supply Voltage

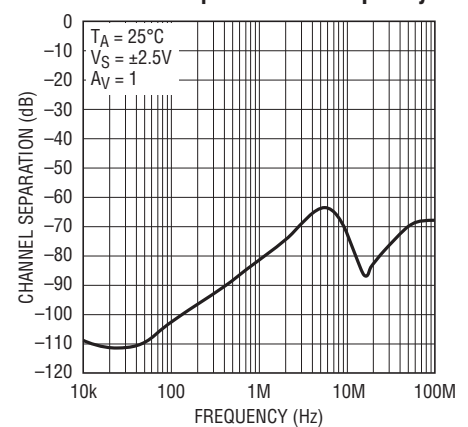
Slew Rate vs Temperature



Output Impedance vs Frequency

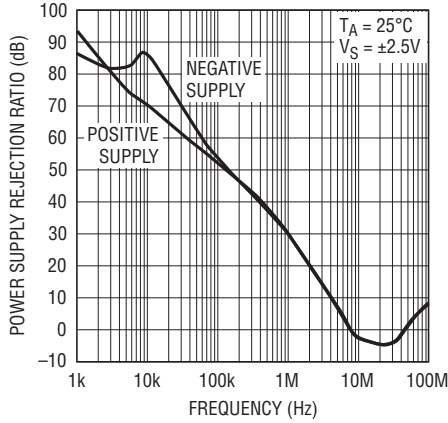
Common Mode Rejection Ratio
vs Frequency

Channel Separation vs Frequency



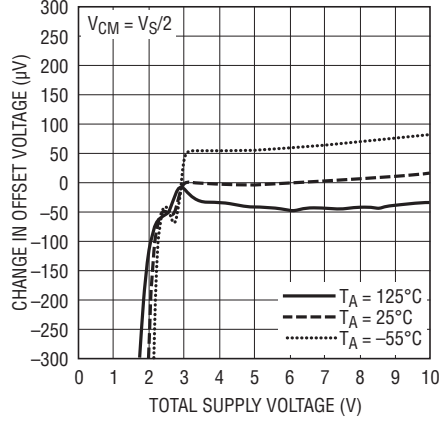
TYPICAL PERFORMANCE CHARACTERISTICS

Power Supply Rejection Ratio vs Frequency



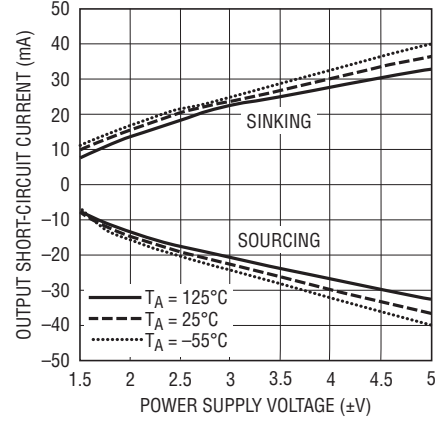
6244 G19

Minimum Supply Voltage



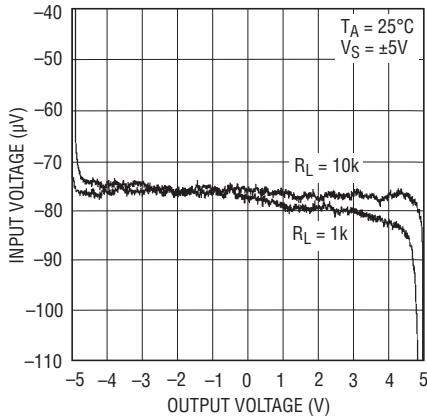
6244 G20

Output Short-Circuit Current vs Power Supply Voltage



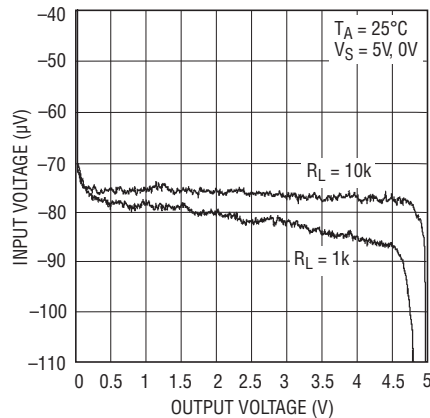
6244 G21

Open-Loop Gain



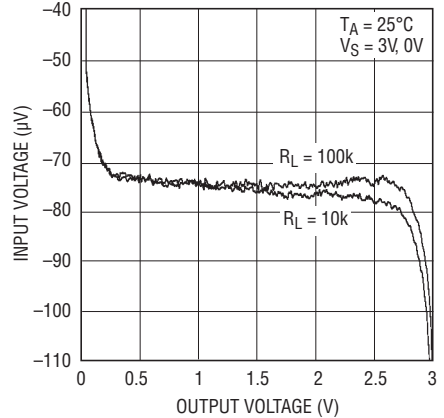
6244 G22

Open-Loop Gain



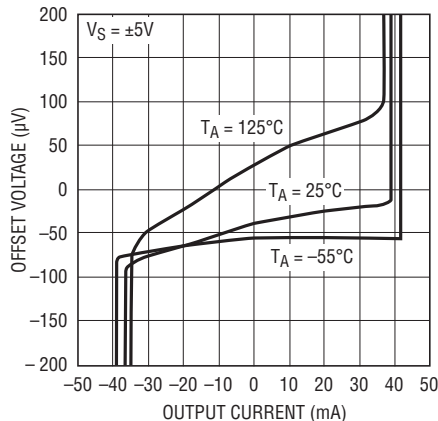
6244 G23

Open-Loop Gain



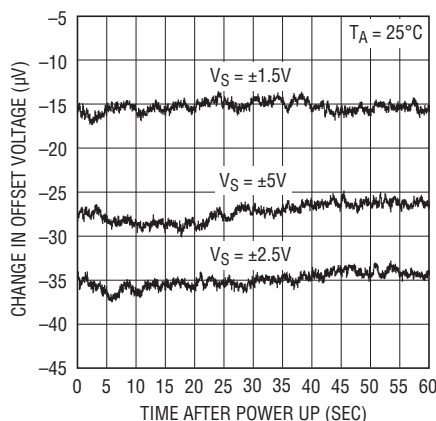
6244 G24

Offset Voltage vs Output Current



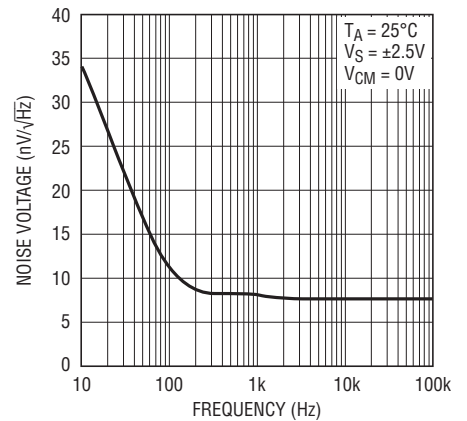
6244 G25

Warm-Up Drift vs Time



6244 G26

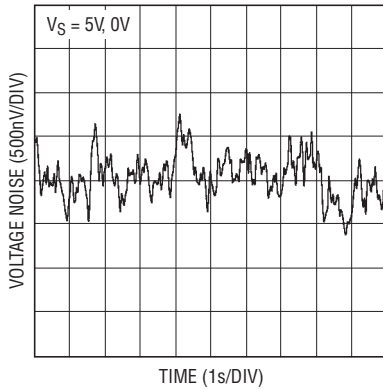
Noise Voltage vs Frequency



6244 G27

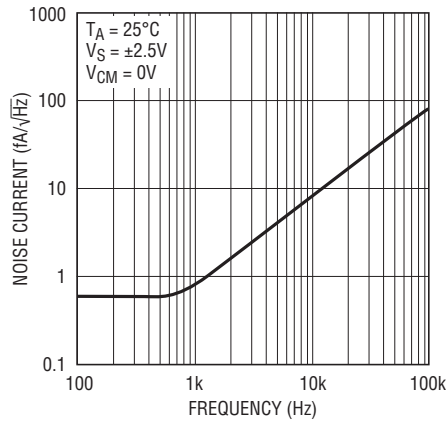
TYPICAL PERFORMANCE CHARACTERISTICS

0.1Hz to 10Hz Voltage Noise



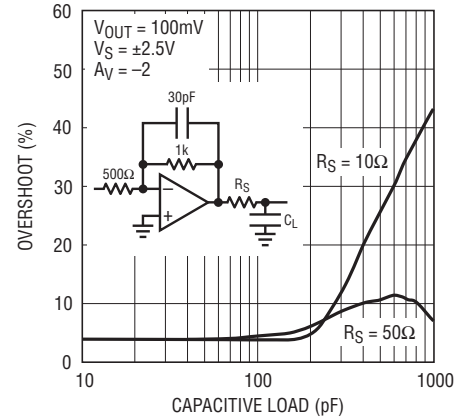
6244 G28

Noise Current vs Frequency



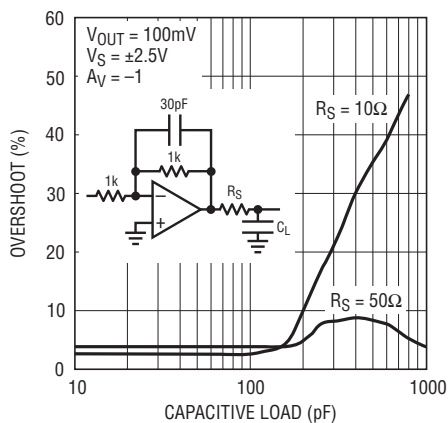
6244 G29

Series Output Resistance and Overshoot vs Capacitive Load



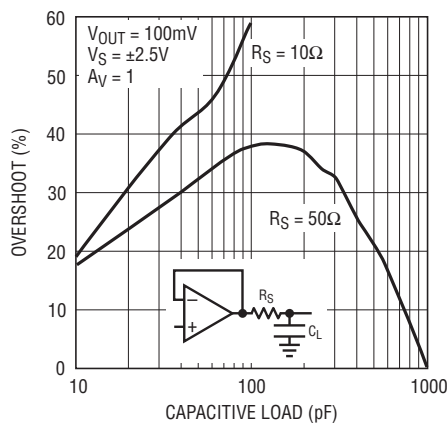
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Series Output Resistance and Overshoot vs Capacitive Load



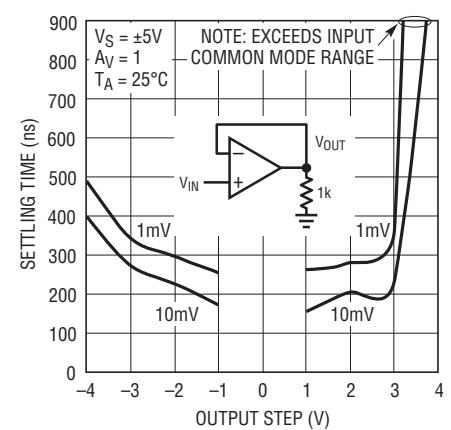
6244 G31

Series Output Resistance and Overshoot vs Capacitive Load



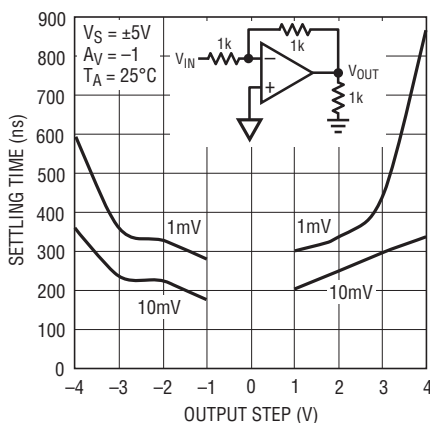
6244 G32

Settling Time vs Output Step (Noninverting)



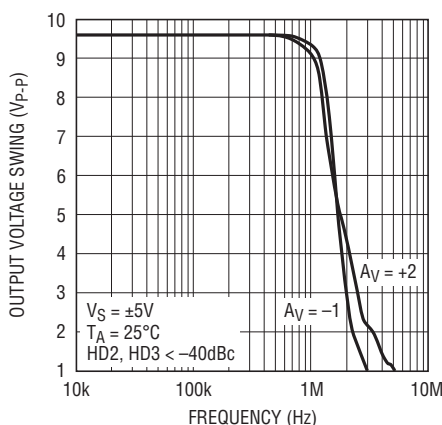
6244 G33

Settling Time vs Output Step (Inverting)



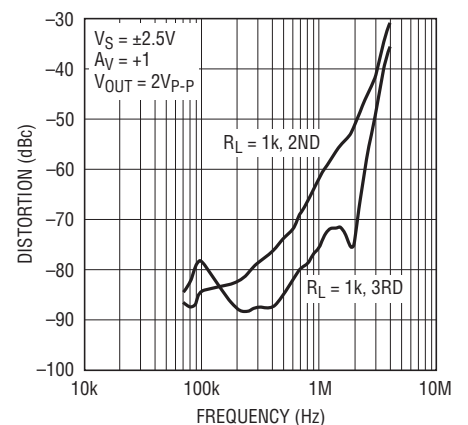
6244 G34

Maximum Undistorted Output Signal vs Frequency



6244 G35

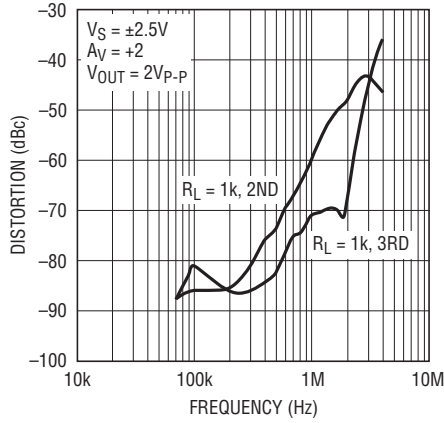
Distortion vs Frequency



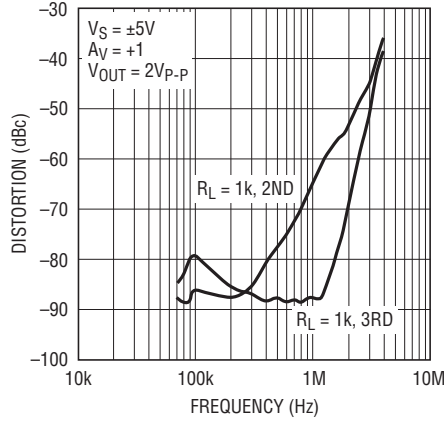
6244 G36

TYPICAL PERFORMANCE CHARACTERISTICS

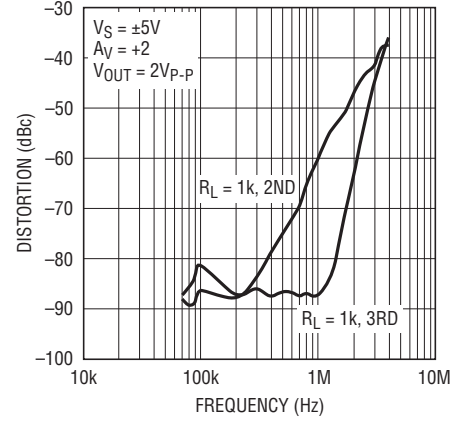
Distortion vs Frequency



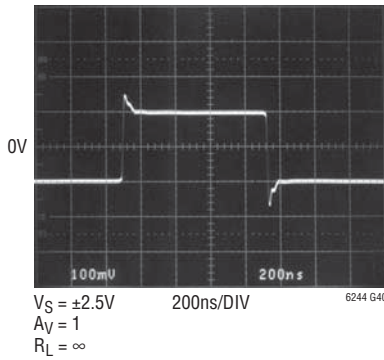
Distortion vs Frequency



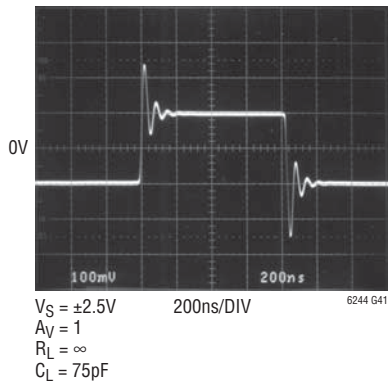
Distortion vs Frequency



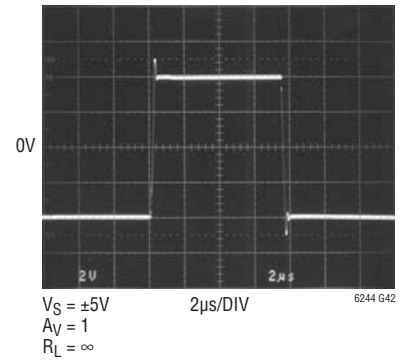
Small-Signal Response



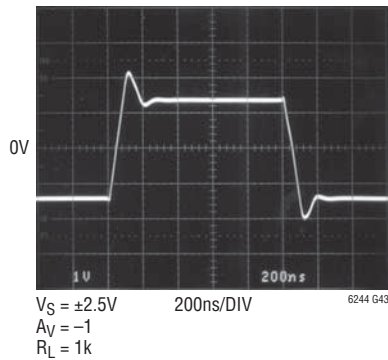
Small-Signal Response



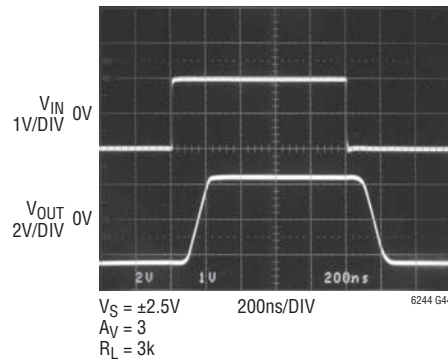
Large-Signal Response



Large-Signal Response



Output Overdrive Recovery



APPLICATIONS INFORMATION

Amplifier Characteristics

Figure 1 is a simplified schematic of the LTC6244, which has a pair of low noise input transistors M1 and M2. A simple folded cascode Q1, Q2 and R1, R2 allow the input stage to swing to the negative rail, while performing level shift to the Differential Drive Generator. Low offset voltage is accomplished by laser trimming the input stage.

Capacitor C1 reduces the unity cross frequency and improves the frequency stability without degrading the gain bandwidth of the amplifier. Capacitor C_M sets the overall amplifier gain bandwidth. The differential drive generator supplies signals to transistors M3 and M4 that swing the output from rail-to-rail.

The photo of Figure 2 shows the output response to an input overdrive with the amplifier connected as a voltage follower. If the negative going input signal is less than a diode drop below V^- , no phase inversion occurs. For input signals greater than a diode drop below V^- , limit the current to 3mA with a series resistor R_S to avoid phase inversion.

The input common mode voltage range extends from V^- to $V^+ - 1.5V$. In unity gain voltage follower applications, exceeding this range by applying a signal that reaches 1V from the positive supply rail can create a low level instability at the output. Loading the amplifier with several hundred micro-amps will reduce or eliminate the instability.

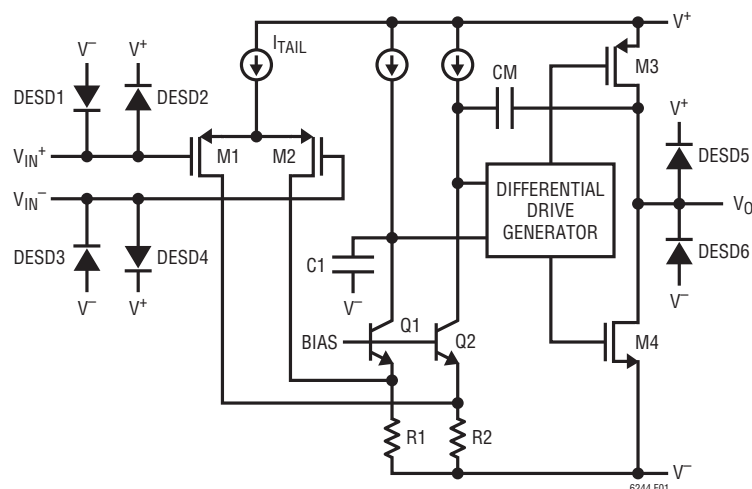


Figure 1. Simplified Schematic

ESD

The LTC6244 has reverse-biased ESD protection diodes on all input and outputs as shown in Figure 1. These diodes protect the amplifier for ESD strikes to 4kV. If these pins are forced beyond either supply, unlimited current will flow through these diodes. If the current transient is less than 1 second and limited to one hundred milliamps or less, no damage to the device will occur.

The amplifier input bias current is the leakage current of these ESD diodes. This leakage is a function of the temperature and common mode voltage of the amplifier, as shown in the Typical Performance Characteristics.

Noise

The LTC6244 exhibits low 1/f noise in the 0.1Hz to 10Hz region. This $1.5\mu V_{P-P}$ noise allows these op amps to be used in a wide variety of high impedance low frequency applications, where Zero-Drift amplifiers might be inappropriate due to their input sampling characteristic.

In the frequency region above 1kHz the LTC6244 also shows good noise voltage performance. In this frequency region, noise can easily be dominated by the total source

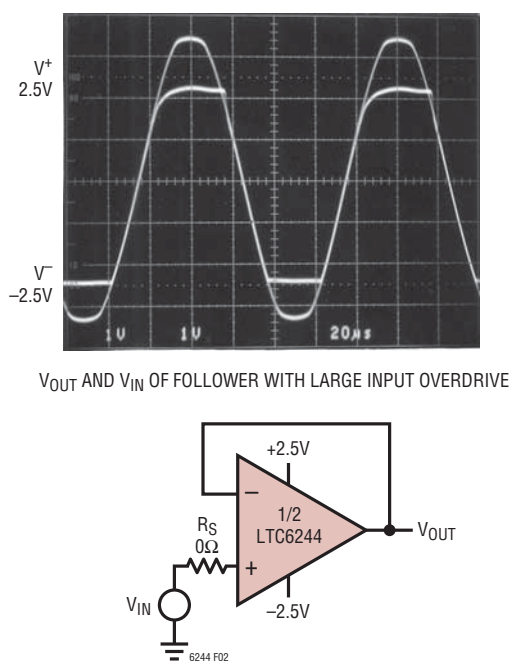


Figure 2. Unity Gain Follower Test Circuit

APPLICATIONS INFORMATION

resistance of the particular application. Specifically, these amplifiers exhibit the noise of a 4k resistor, meaning it is desirable to keep the source and feedback resistance at or below this value, i.e., $R_S + R_G || R_{FB} \leq 4k$. Above this total source impedance, the noise voltage is not dominated by the amplifier.

Noise current can be estimated from the expression $i_n = \sqrt{2qI_B}$, where $q = 1.6 \cdot 10^{-19}$ coulombs. Equating $\sqrt{4kTR\Delta f}$ and $R_S\sqrt{2qI_B\Delta f}$ shows that for source resistors below $50G\Omega$ the amplifier noise is dominated by the source resistance. See the Typical Characteristics curve Noise Current vs Frequency.

Proprietary design techniques are used to obtain simultaneous low $1/f$ noise and low input capacitance. Low input capacitance is important when the amplifier is used with high source and feedback resistors. High frequency noise from the amplifier tail current source, I_{TAIL} in Figure 1, couples through the input capacitance and appears across these large source and feedback resistors.

Stability

The good noise performance of these op amps can be attributed to large input devices in the differential pair. Above several hundred kilohertz, the input capacitance can cause amplifier stability problems if left unchecked. When the feedback around the op amp is resistive (R_F), a pole will be created with R_F , the source resistance, source capacitance (R_S , C_S), and the amplifier input capacitance.

In low gain configurations and with R_F and R_S in even the kilohm range (Figure 3), this pole can create excess phase shift and possibly oscillation. A small capacitor C_F in parallel with R_F eliminates this problem.

Achieving Low Input Bias Current

The DD package is leadless and makes contact to the PCB beneath the package. Solder flux used during the attachment of the part to the PCB can create leakage current paths and can degrade the input bias current performance of the part. All inputs are susceptible because the backside paddle is connected to V^- internally. As the input voltage changes or if V^- changes, a leakage path can be formed and alter the observed input bias current. For lowest bias current, use the LTC6244 in the MS8 package.

Photodiode Amplifiers

Photodiodes can be broken into two categories: large area photodiodes with their attendant high capacitance (30pF to 3000pF) and smaller area photodiodes with relatively low capacitance (10pF or less). For optimal signal-to-noise performance, a transimpedance amplifier consisting of an inverting op amp and a feedback resistor is most commonly used to convert the photodiode current into voltage. In low noise amplifier design, large area photodiode amplifiers require more attention to reducing op amp input voltage noise, while small area photodiode amplifiers require more attention to reducing op amp input current noise and parasitic capacitances.

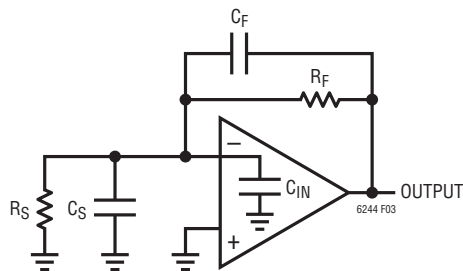


Figure 3. Compensating Input Capacitance

APPLICATIONS INFORMATION

Large Area Photodiode Amplifiers

A simple large area photodiode amplifier is shown in Figure 4a. The capacitance of the photodiode is 3650pF (nominally 3000pF), and this has a significant effect on the noise performance of the circuit. For example, the photodiode capacitance at 10kHz equates to an impedance of 4.36k Ω , so the op amp circuit with 1M Ω feedback has a noise gain of $NG = 1 + 1M/4.36k = 230$ at that frequency. Therefore, the LTC6244 input voltage noise gets to the output as $NG \cdot 7.8nV/\sqrt{Hz} = 1800nV/\sqrt{Hz}$, and this can clearly be seen in the circuit's output noise spectrum in Figure 4b. Note that we have not yet accounted for the op amp current noise, or for the 130nV/ \sqrt{Hz} of the gain resistor, but these are obviously trivial compared to the op

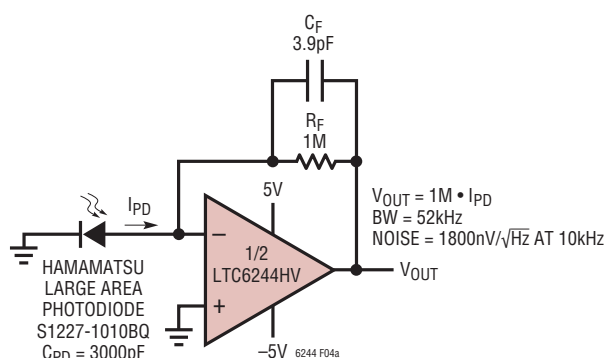


Figure 4a. Large Area Photodiode Transimpedance Amplifier

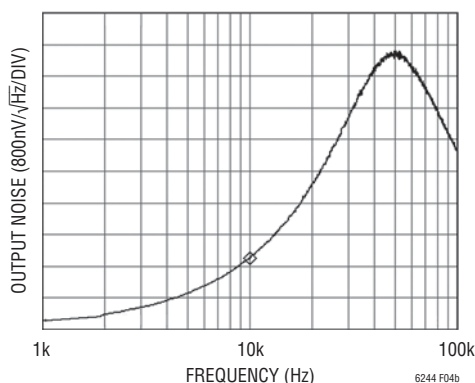


Figure 4b. Output Noise Spectral Density of the Circuit of Figure 4a. At 10kHz, the 1800nV/ \sqrt{Hz} Output Noise is Due Almost Entirely to the 7.8nV Voltage Noise of the LTC6244 and the High Noise Gain of the 1M Feedback Resistor Looking Into the High Photodiode Capacitance

amp voltage noise and the noise gain. For reference, the DC output offset of this circuit is about 100 μ V, bandwidth is 52kHz, and the total noise was measured at 1.7mV_{RMS} on a 100kHz measurement bandwidth.

An improvement to this circuit is shown in Figure 5a, where the large diode capacitance is bootstrapped by a 1nV/ \sqrt{Hz} JFET. This depletion JFET has a V_{GS} of about -0.5V, so that R_{BIAS} forces it to operate at just over 1mA of drain current. Connected as shown, the photodiode has a reverse bias of one V_{GS} , so its capacitance will be slightly lower than in the previous case (measured 2640pF), but the most drastic effects are due to the bootstrapping. Figure 5b shows the output noise of the new circuit. Noise at 10kHz is now 220nV/ \sqrt{Hz} , and the 130nV/ \sqrt{Hz} noise thermal noise floor of the 1M feedback resistor is discernible at low frequencies. What has happened is that the 7.8nV/ \sqrt{Hz} of the op amp has been effectively replaced by the 1nV/ \sqrt{Hz} of the JFET. This is because the 1M feedback resistor is no longer “looking back” into the large photodiode capacitance. It is instead looking back into a JFET gate capacitance, an op amp input capacitance, and some parasitics, approximately 10pF total. The large photodiode capacitance is across the gate-source voltage of the low noise JFET. Doing a sample calculation at 10kHz as before, the photodiode capacitance looks like 6k Ω , so the 1nV/ \sqrt{Hz} of the JFET creates a current noise of $1nV/6k = 167fA/\sqrt{Hz}$. This current noise necessarily flows through the 1M feedback resistor, and so appears as 167nV/ \sqrt{Hz} at the output. Adding the 130nV/ \sqrt{Hz} of the resistor (RMS wise) gives a total calculated noise density of 210nV/ \sqrt{Hz} , agreeing well with the measured noise of Figure 5b. Another drastic improvement is in bandwidth, now over 350kHz, as the bootstrap enabled a reduction of the compensating feedback capacitance. Note that the bootstrap does not affect the DC accuracy of the amplifier, except by adding a few picoamps of gate current.

There is one drawback to this circuit. Most photodiode circuits require the ability to set the amount of applied reverse bias, whether it's 0V, 5V, or 200V. This circuit has a fixed reverse bias of about 0.5V, dictated by the JFET.

APPLICATIONS INFORMATION

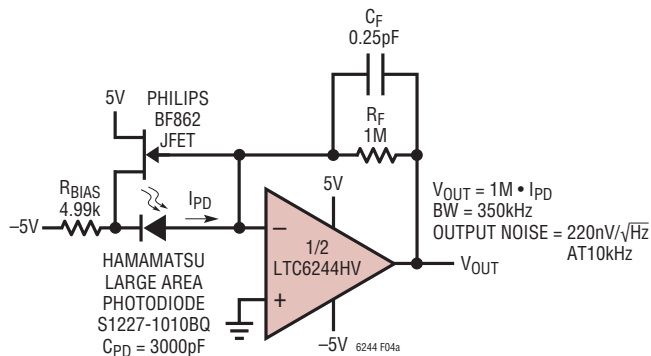


Figure 5a. Large Area Diode Bootstrapping

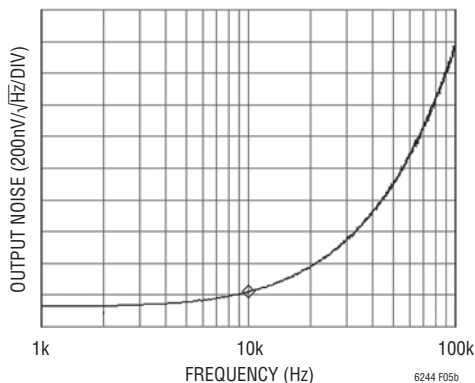


Figure 5b: Output Noise Spectral Density of Figure 5a. The Simple JFET Bootstrap Improves Noise (and Bandwidth) Drastically. Noise Density at 10kHz is Now 220nV/√Hz, About a 8.2x Reduction. This is Mostly Due to the Bootstrap Effect of Swapping the 1nV/√Hz of the JFET for the 7.8nV/√Hz of the Op Amp

The solution is as shown in the circuit of Figure 6a, which uses a capacitor-resistor pair to enable the AC benefits of bootstrapping while allowing a different reverse DC voltage on the photodiode. The JFET is still running at the same current, but an arbitrary reverse bias may be applied to the photodiode. The output noise spectrum of the circuit with 0V of photodiode reverse bias is shown in Figure 6b. Photodiode capacitance is again 3650pF, as in the original circuit of Figure 4a. This noise plot with 0V bias shows that bootstrapping alone was responsible for a factor of 6.2 noise reduction, from 1800nV/√Hz to 291nV/√Hz at 10kHz, independent of photodiode capacitance. However, photodiode capacitance can now be reduced arbitrarily

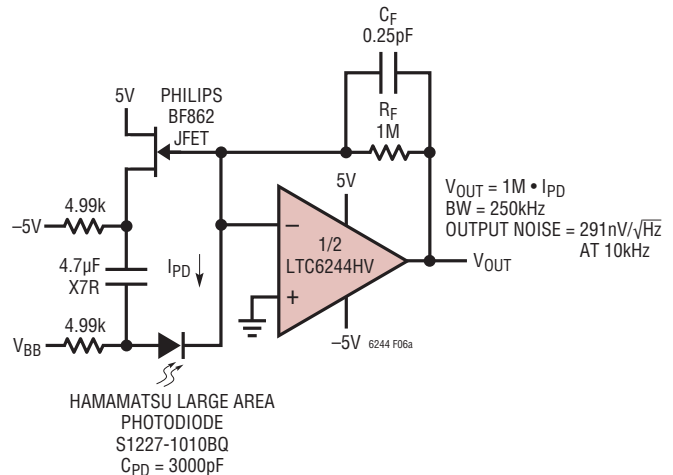


Figure 6a. The Addition of a Capacitor and Resistor Enable the Benefit of Bootstrapping While Applying Arbitrary Photodiode Bias Voltage V_{BB}

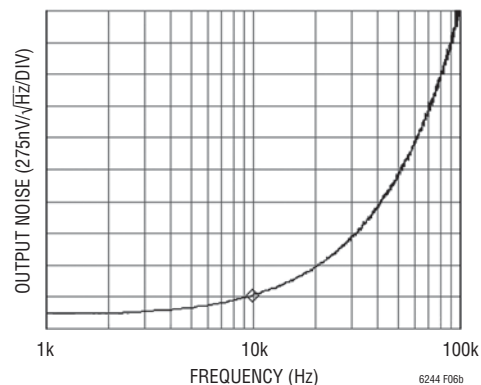


Figure 6b: Output Spectrum of Circuit of Figure 6a, with Photodiode Bias at 0V. Photodiode Capacitance is Back Up, as in the Original Circuit of Figure 4a. However, it can be Reduced Arbitrarily by Providing Reverse Bias. This Plot Shows that Bootstrapping Alone Reduced the 10kHz Noise Density by a Factor of 6.2, from 1800nV/√Hz to 291nV/√Hz

by providing reverse bias, and the photodiode can also be reversed to support either cathode or anode connections for positive or negative going outputs.

The circuit on the last page of this data sheet shows further reduction in noise by paralleling four JFETs to attain 152nV/√Hz at 10kHz, a noise of 12 times less than the basic photodiode circuit of Figure 4a.

APPLICATIONS INFORMATION

Small Area Photodiode Amplifiers

Small area photodiodes have very low capacitance, typically under 10pF and some even below 1pF. Their low capacitance makes them more approximate current sources to higher frequencies than large area photodiodes. One of the challenges of small area photodiode amplifier design is to maintain low input capacitance so that voltage noise does not become an issue and current noise dominates. A simple small area photodiode amplifier using the LTC6244 is shown in Figure 7. The input capacitance of the amplifier consists of C_{DM} and one C_{CM} (because the +input is

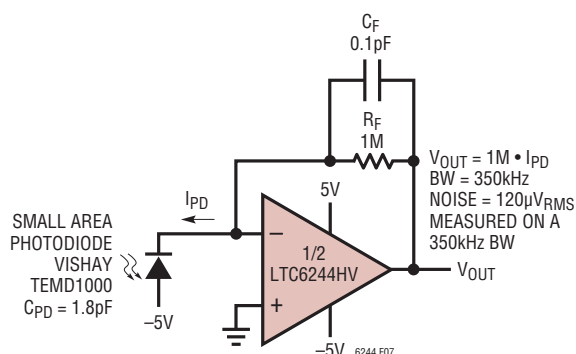


Figure 7. LTC6244 in a Normal TIA Configuration

grounded), or about 6pF total. The small photodiode has 1.8pF, so the input capacitance of the amplifier is dominating the capacitance. The small feedback capacitor is an actual component (AVX Accu-F series), but it is also in parallel with the op amp lead, resistor and parasitic capacitances, so the total real feedback capacitance is probably about 0.4pF. The reason this is important is that this sets the compensation of the circuit and, with op amp gain bandwidth, the circuit bandwidth. The circuit as shown has a bandwidth of 350kHz, with an output noise of 120μV_{RMS} measured over that bandwidth.

The circuit of Figure 8a makes some slight improvements. Operation is still transimpedance mode, with R_F setting the gain to 1MΩ. However, a noninverting input stage A1 with a gain of 3 has been inserted, followed by the usual inverting stage performed by A2. Note what this achieves. The amplifier input capacitance is bootstrapped by the feedback of R2:R1, eliminating the effect of A1's input C_{DM} (3.5pF), and leaving only one C_{CM} (2.1pF). The op amp at Pins 5, 6 and 7 was chosen for the input amplifier to eliminate extra pin-to-pin capacitance on the (+) input. The lead capacitance on the corner of an MSOP package is only about 0.15pF. By using this noninverting configuration, input capacitance is minimized.

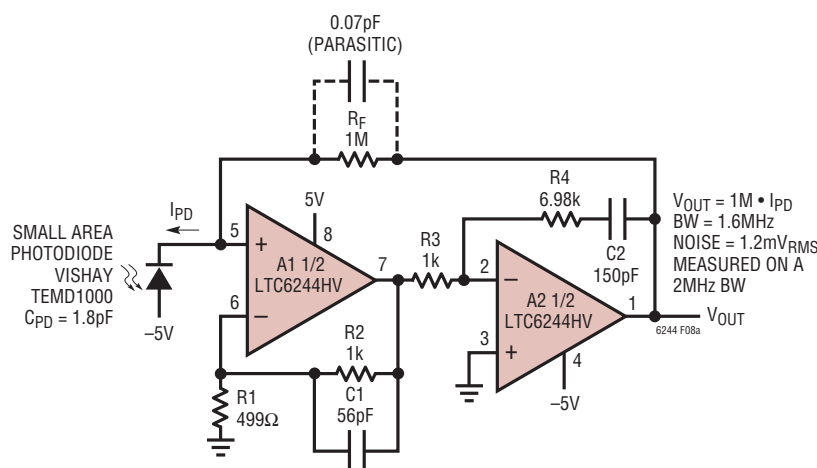


Figure 8a: Using Both Op Amps for Higher Bandwidth. A1 Provides a Gain of 3 Within the Loop, Increasing the Gain Bandwidth Product. This Bootstraps the C_{DM} Across A1's Inputs, Reducing Amplifier Input Capacitance. Inversion is Provided by A2, so that the Photodiode Looks Into a Noninverting Input. Pin 5 was Selected Because it is in the Corner, Removing One Lead Capacitance

APPLICATIONS INFORMATION

Total capacitance at the amplifier's input is now one C_{CM} (2.1pF) plus the photodiode capacitance C_{PD} (1.8pF), or about 4pF accounting for parasitics. The shunt impedance at 1MHz, for example, is $X_C = 1/(2\pi fC) = 39.8k\Omega$, and therefore, the noise gain at 1MHz is $NG = 1 + R_f/X_C = 26$. The input voltage noise of this amplifier is about $15nV/\sqrt{Hz}$, after accounting for the effects of R1 through R3, the noise of the second stage and the fact that voltage noise does rise with frequency. Multiplying the noise gain by the input voltage noise gives an output noise density due to voltage noise of $26 \cdot 15nV/\sqrt{Hz} = 390nV/\sqrt{Hz}$. But the noise spectral density plot of Figure 8b shows an output noise of $782nV/\sqrt{Hz}$ at 1MHz. The extra output noise is due to input current noise, multiplied by the feedback impedance. So while the circuit of Figure 8a does increase bandwidth, it does not offer a noise advantage. Note, however, that the $1.2mV_{RMS}$ of noise is now measured in a 2MHz bandwidth, instead of over a 350kHz bandwidth of the previous example.

A Low Noise Fully Differential Buffer/Amplifier

In differential signal conditioning circuits, there is often a need to monitor a differential source without loading or

adding appreciable noise to the circuit. In addition, adding gain to low level signals over appreciable bandwidth is extremely useful. A typical application for a low noise, high impedance, differential amplifier is in the baseband circuit of an RFID (radio frequency identification) receiver. The baseband signal of a UHF RFID receiver is typically a low level differential signal at the output of a demodulator with differential output impedance in the range of 100Ω to 400Ω . The bandwidth of this signal is 1MHz or less.

The circuit of Figure 9a uses an LTC6244 to make a low noise fully differential amplifier. The amplifier's gain, input impedance and $-3dB$ bandwidth can be specified independently. Knowing the desired gain, input impedance and $-3dB$ bandwidth, R_G , C_F and C_{IN} can be calculated from the equations shown in Figure 9b. The common mode gain of this amplifier is equal to one ($V_{OUTCM} = V_{INCM}$) and is independent of resistor matching. The component values in the Figure 9a circuit implement a 970kHz, gain = 5, differential amplifier with 4k input impedance. The output differential DC offset is typically less than $500\mu V$. The differential input referred noise voltage density is shown in Figure 10. The total input referred noise in a 1MHz bandwidth is $16\mu V_{RMS}$.

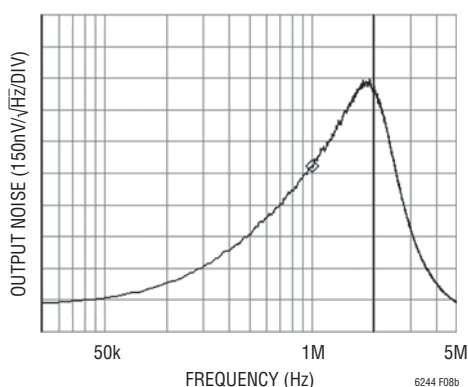


Figure 8b: Output Noise Spectrum of the Circuit in Figure 8a.
Noise at 1MHz is $782nV/\sqrt{Hz}$, Due Mostly to the Input Current Noise Rising with Frequency

APPLICATIONS INFORMATION

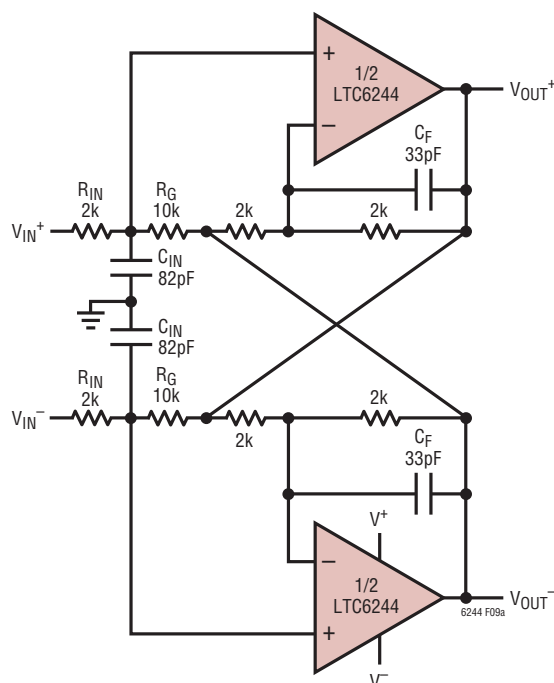


Figure 9a. Low Noise Fully Differential Buffer/Amplifier
($f_{-3dB} = 970\text{kHz}$, Gain = 5, $R_{IN} = 4\text{k}$)

$$\text{Input Impedance} = 2 \cdot R_{IN}$$

$$\text{Gain} = \frac{V_{OUT+} - V_{OUT-}}{V_{IN+} - V_{IN-}} = \frac{R_G}{R_{IN}}$$

$$\text{Maximum Gain} = \frac{5\text{MHz}}{f_{3dB}}$$

$$C_F = \frac{1}{4398 \cdot f_{3dB} \cdot (\text{Gain} + 2)}$$

$$C_{IN} = \frac{\text{Gain} + 2}{8.977 \cdot \text{Gain} \cdot R_{IN} \cdot f_{3dB}}$$

$$f_{3dB} = \frac{1}{\sqrt{4000 \cdot \pi^2 \cdot R_G \cdot C_F \cdot C_{IN}}}$$

Figure 9b. Design Equations for Figure 9a Circuit

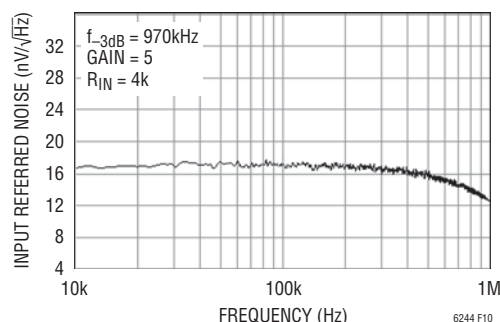


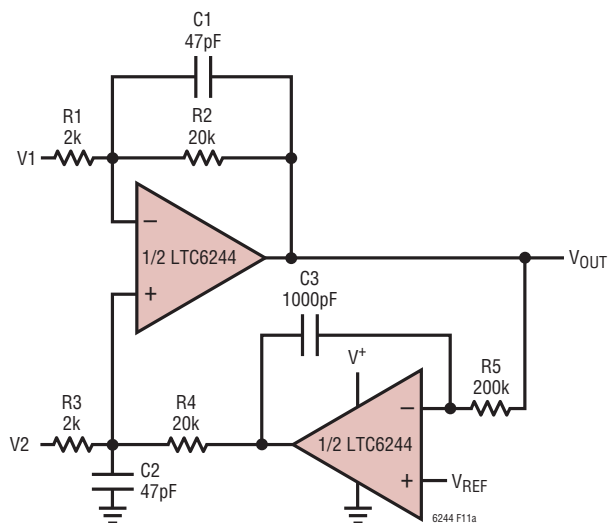
Figure 10. Differential Input Referred Noise

A Low Noise AC Difference Amplifier

In the signal conditioning of wideband sensors and transducers, a low noise amplifier is often used to provide gain for low level AC difference signals in the frequency range of a few Hertz to hundreds of kilo-Hertz. In addition, the amplifier must reject common mode AC signals and its input impedance should be higher than the differential source impedance. Typical applications are piezoelectric sensors used in sonar, sound and ultrasound systems and LVDT (linear variable differential transformers) for displacement measurements in process control and robotics.

The Figure 11a circuit is a low noise, single supply AC difference amplifier. The amplifier's low frequency -3dB bandwidth is set with resistor R_5 and capacitor C_3 , while the upper -3dB bandwidth is set with R_2 and C_1 . The input common mode DC voltage can vary from ground to V^+ and the output DC voltage is equal to the V_{REF} voltage. The amplifier's gain is the ratio of resistors R_2 to R_1 ($R_4 = R_2$ and $R_3 = R_1$). The component values in the circuit of Figure 11a implement an 800Hz to 160kHz AC amplifier with a gain equal to 10 and $12\text{nV}/\sqrt{\text{Hz}}$ input referred voltage noise density shown in Figure 11b. The total input referred wideband noise is $4.5\mu\text{VRMS}$, in the bandwidth of 500Hz to 200kHz .

APPLICATIONS INFORMATION



$$V_{OUT} = \text{GAIN} \cdot (V2 - V1) + V_{REF}$$

$$\text{GAIN} = \frac{R2}{R1} \quad R3 = R1, R4 = R2, C1 = C2$$

$$\text{BANDWIDTH} = f_{HI} - f_{LO}$$

$$f_{HI} = \frac{1}{2 \cdot \pi \cdot R2 \cdot C1}, \quad f_{LO} = \frac{1}{2 \cdot \pi \cdot R5 \cdot C3}$$

**Figure 11a. Low Noise AC Difference Amplifier
(Bandwidth 800Hz to 160kHz, Gain = 10)**

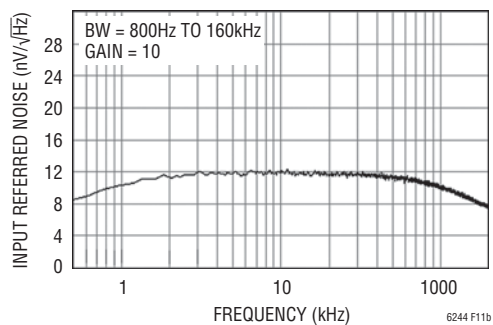
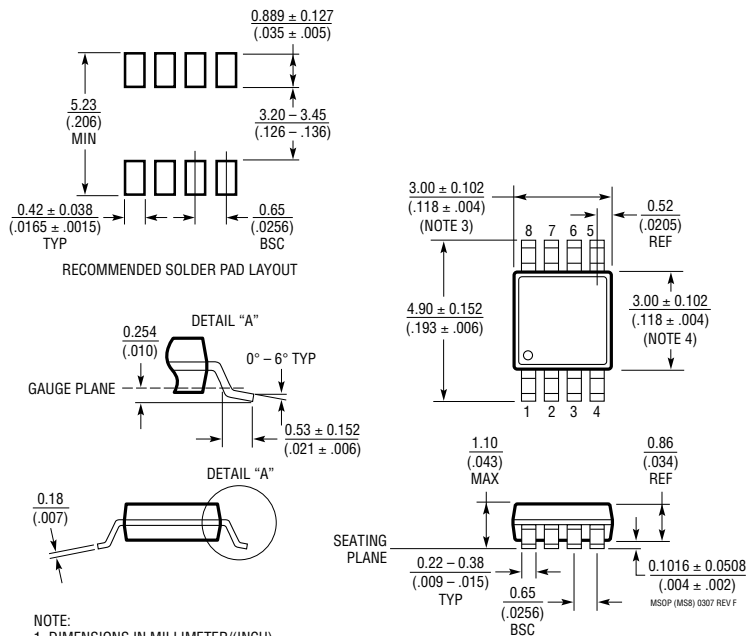


Figure 11b. Input Referred Noise

MS8 Package
8-Lead Plastic MSOP
 (Reference LTC DWG # 05-08-1660 Rev F)

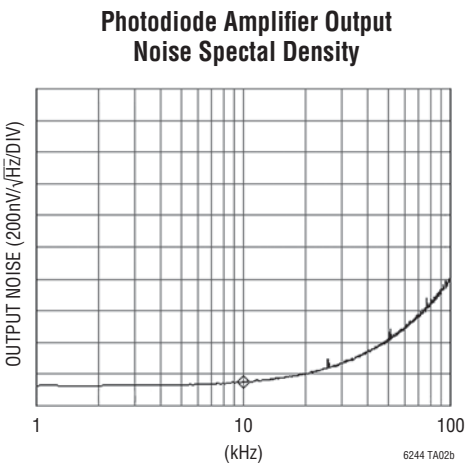
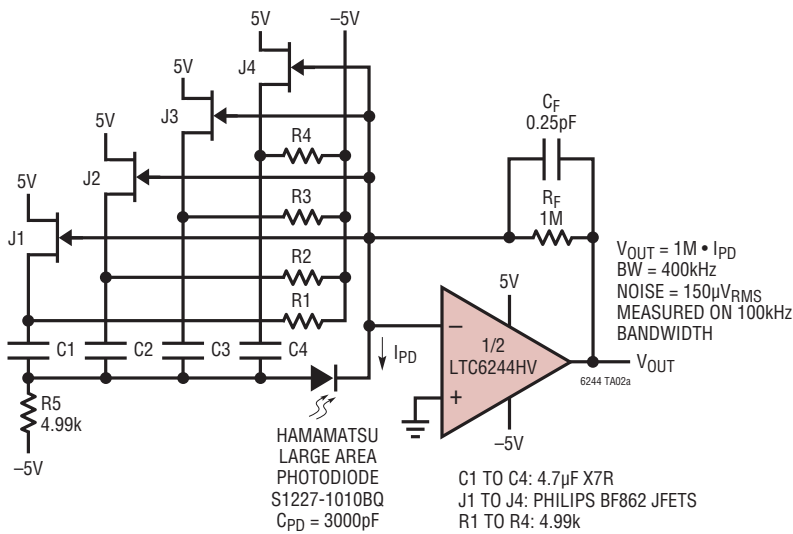


REVISION HISTORY (Revision history begins at Rev B)

REV	DATE	DESCRIPTION	PAGE NUMBER
B	12/09	Change to Figure 2	15

TYPICAL APPLICATION

Ultralow Noise Large Area Photodiode Amplifier



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LTC1151	±15V Zero-Drift Op Amp	Dual High Voltage Operation ±18V
LT1792	Low Noise Precision JFET Op Amp	6nV/√Hz Noise, ±15V Operation
LTC2050	Zero-Drift Op Amp	2.7 Volt Operation, SOT-23
LTC2051/LTC2052	Dual/Quad Zero-Drift Op Amp	Dual/Quad Version of LTC2050 in MS8/GN16 Packages
LTC2054/LTC2055	Single/Dual Zero-Drift Op Amp	Micropower Version of the LTC2050/LTC2051 in SOT-23 and DD Packages
LTC6087/LTC6088	Dual/Quad 14MHz CMOS Op Amps	Rail-to-Rail, Low Cost
LTC6240/LTC6241/LTC6242	Single/Dual/Quad, 18MHz CMOS Op Amps	Low Noise, Rail-to-Rail